

DIO7910Q

300 mA, Ultra-Low-Noise, Low-IQ LDO

Features

- Operating Input Voltage Range: 1.6 V to 5.5 V
- Output Voltage: 1.2 V
- Output current: 300 mA
- Ultra-Low Quiescent Current: Typ. 25 μ A
- Dropout voltage : 600 mV at $I_{OUT}=300$ mA
- PSRR: 75dB at 1 kHz, $I_{OUT} = 20$ mA
- Output Voltage Tolerance: $\pm 2\%$
- Stable with Ceramic Capacitors 1 μ F
- Thermal-Overload Protection
- Short-Circuit Protection
- Quick Output Discharge
- DIO7910QA: available
- DIO7910QB: not available
- Available in Small DFN1*1-4, SOT23-5, and DFN0.8*0.8-4 Packages
- These Devices are Pb-Free, Halogen Free/BFR Free, and are RoHS Compliant

Descriptions

The DIO7910Q is a high-accuracy, low-noise, high-speed, high PSRR, and low-dropout CMOS Linear regulator with high ripple rejection. The devices offer a new level of cost-effective performance in cellular phones, laptop and notebook computers, and other portable devices.

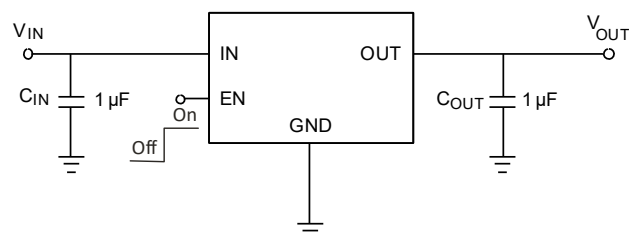
The DIO7910Q has the fold-back maximum output current that depends on the output voltage. So the current limit function short circuit protection and an output current limiter.

The device is available in DFN1*1-4, SOT23-5, and DFN0.8*0.8-4 packages.

Applications

- MP3/MP4 Players
- Cellphones, Radiophone, Digital Cameras
- Bluetooth, Wireless Handsets
- Others portable electronics devices

Typical Applications



Ordering Information

Order Part Number	Top Marking		T_A	Package	
DIO7910QA12ST5	QAFYW	Green	-40 to 85°C	SOT23-5	Tape & Reel,3000
DIO7910QA12EN4	KFYW	Green	-40 to 85°C	DFN1*1-4	Tape & Reel,10000
DIO7910QA12CN4	D	Green	-40 to 85°C	DFN0.8*0.8-4	Tape & Reel,5000
DIO7910QB12ST5	QBFYW	Green	-40 to 85°C	SOT23-5	Tape & Reel,3000
DIO7910QB12EN4	VFYW	Green	-40 to 85°C	DFN1*1-4	Tape & Reel,10000
DIO7910QB12CN4	D	Green	-40 to 85°C	DFN0.8*0.8-4	Tape & Reel,5000

Pin Assignments

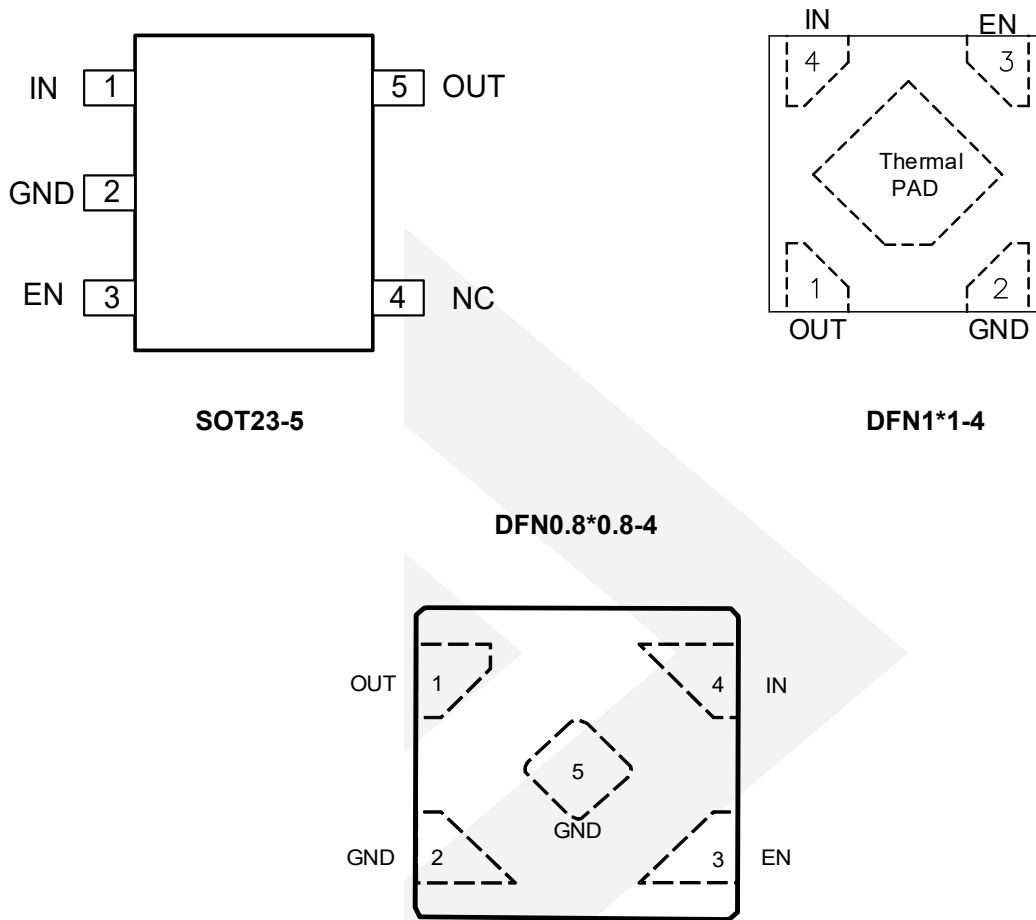


Figure 1. Pin Assignment (Top View)

Pin Definitions

Pin Name	Description
OUT	Output Voltage Pin
EN	Enable Pin. This pin has an internal pull-down resistor. A logic low reduces the supply current to less than 1 μ A. Connect to logic "High" for normal operation.
GND	Power Supply Ground
IN	Input Voltage Pin
NC	No connection

Absolute Maximum Ratings

Stresses beyond those listed under the Absolute Maximum Rating table may cause permanent damage to the device. These are stress ratings only and functional operation of the device at these or any other condition beyond those indicated in the operational sections of the specifications is not implied. Exposure to absolute maximum rating conditions for extended periods may affect device reliability.

Parameter		Rating	Unit
Input Voltage V_{IN}		-0.3 to 6.5	V
Output Voltage V_{OUT}		-0.3 to V_{IN}	V
Chip Enable Input V_{EN}		-0.3 to V_{IN}	V
Output Current I_{OUT}		300	mA
Lead Temperature Range		260	°C
Operating Junction Temperature $T_{J(MAX)}$		150	°C
Storage Temperature T_{STG}		-55 to 150	°C
MSL		Level-3	
ESD	HBM	8000	V
	MM	300	

Recommend Operating Ratings

The Recommended Operating Conditions table defines the conditions for actual device operation. Recommended operating conditions are specified to ensure optimal performance to the datasheet specifications. DIOO does not recommend exceeding them or designing to absolute maximum ratings.

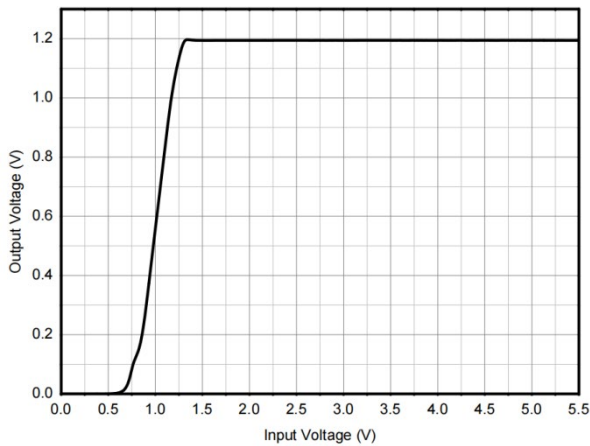
Parameter		Rating	Unit
Operating Supply voltage		1.6~5.5	V
Operating Temperature Range		-40~85	°C
Thermal Resistance, $R_{\theta JA}$	SOT23-5	235	°C/W
	DFN1*1-4	250	
	DFN0.8*0.8-4	400	

Electrical Characteristics

$T_A=25^{\circ}\text{C}$, $V_{IN} = V_{OUT}+1\text{ V}$, $I_{OUT}=1\text{ mA}$, $C_{IN}=C_{OUT}=1.0\text{ }\mu\text{F}$, unless otherwise specified.

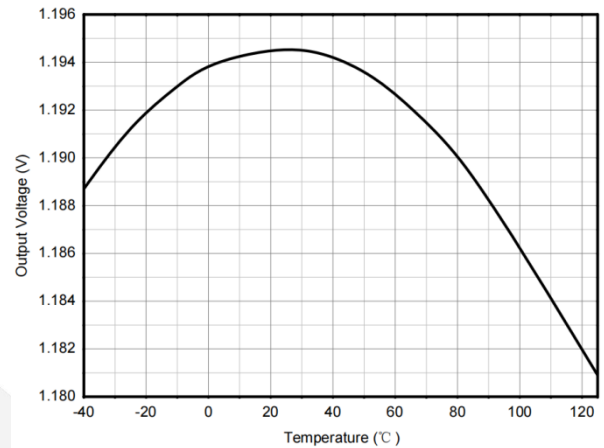
Symbol	Parameter	Condition		Min	Typ	Max	Unit
V _{IN}	Input Voltage			1.6		5.5	V
V _{OUT}	Output Voltage				1.2		V
	Output Accuracy	V _{OUT} = 1. 2 V, I _L =10 mA, T _J = -40°C to 85°C		-2%	V _{OUT}	+2%	mV
I _{LIM}	Output Current Limit	V _{OUT} = 90% V _{OUT(NOM)}			480		mA
V _{DROP}	Dropout Voltage	V _{IN} = 0.98 x V _{OUT(SET)} , I _{OUT} =300 mA	V _{OUT(SET)} =1.2 V		600		mV
$\frac{\Delta V_{OUT}}{\Delta V_{IN} \times V_{OUT}}$	Line Regulation	V _{OUT(NOM)} + 1.0 V ≤ V _{IN} ≤ 5.5 V			0.02		%/V
ΔV _{OUT}	Load Regulation	I _{OUT} = 0 mA to 350 mA, T _A = +25°C				40	mV
I _Q	Quiescent Current	No load			25		μA
I _{SC}	Short Circuit Current	V _{OUT} = 0 V			220		mA
I _{SHDN}	Shut-down Current	V _{EN} = 0 V, V _{IN} = 5.5 V			0.1		μA
PSRR	Power Supply Rejection Rate	I _{OUT} = 20 mA	f=100 Hz		80		dB
			f=1 kHz		75		dB
			f=10 kHz		70		dB
			f=100 kHz		60		dB
			f=1 MHz		45		dB
V _{IH}	EN Pin Threshold Voltage	EN logic high voltage		1			V
V _{IL}		EN logic low voltage				0.4	V
I _{EN}	EN Pull-Down Current	V _{EN} = 5.5 V			0.1		μA
e _n	Output Voltage Noise	f = 10 Hz to 100 kHz, V _{OUT} =2.8 V, I _{OUT} =1 mA			70		μV _{RMS}
T _{SD}	Thermal shutdown threshold	Shutdown, temperature increasing	I _{OUT} =1 mA		175		°C
		Reset, temperature decreasing			145		
R _{DISCH}	Output Discharge Resistance	V _{EN} ≤0.2 V, V _{IN} =5 V (only A version)			100		Ω
t _{ON}	Turn-On Time	From assertion of V _{EN} to V _{OUT} = 90% V _{OUT(NOM)}			120		μs

Typical Performance Characteristics



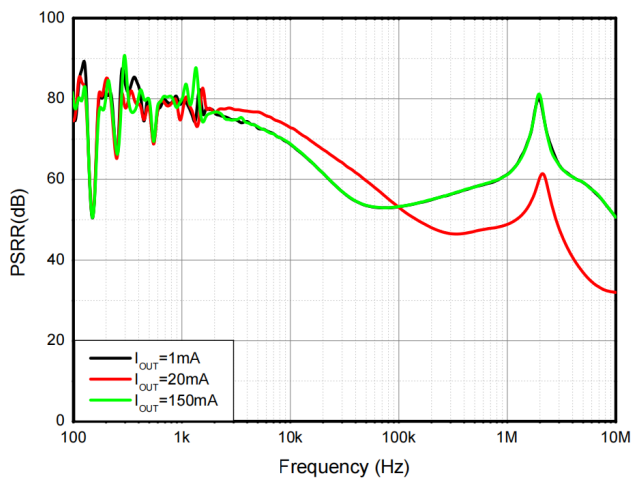
$C_{IN} = C_{OUT} = 1 \mu F$, $I_{OUT} = 1 \text{ mA}$, $V_{OUT} = 1.2 \text{ V}$

Figure 2. Output Voltage vs Input Voltage



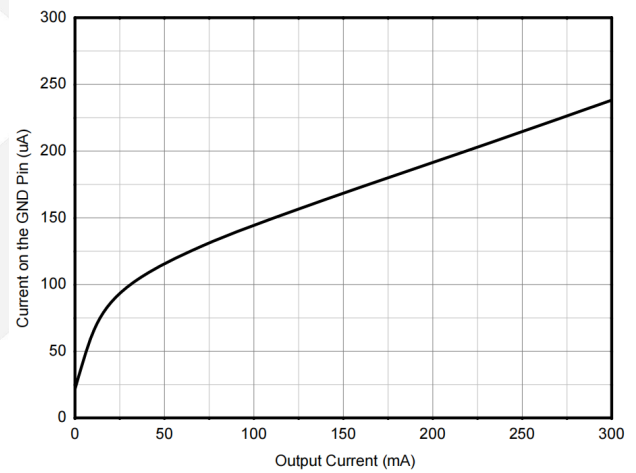
$V_{OUT} = 1.2 \text{ V}$, $C_{IN} = C_{OUT} = 1 \mu F$, $I_{OUT} = 1 \text{ mA}$

Figure 3. Output Voltage vs Temperature



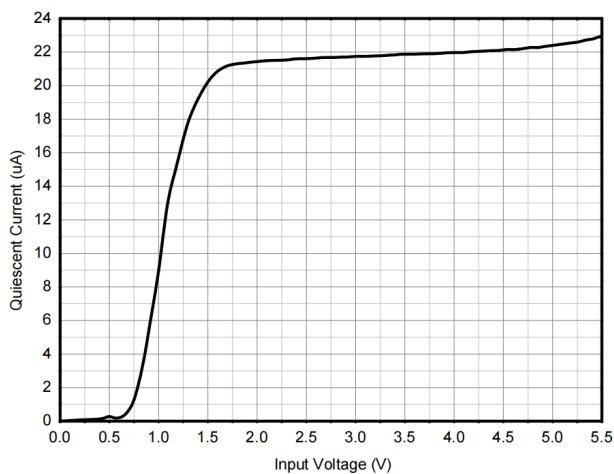
$C_{OUT} = 1 \mu F$, $V_{IN} = 2.5 \text{ V} + 200 \text{ mVpp}$, $V_{OUT} = 1.2 \text{ V}$

Figure 4. PSRR vs Frequency



$C_{OUT} = 1 \mu F$, $V_{IN} = V_{OUT} + 1 \text{ V}$ or 2.5 V whichever is higher

Figure 5. Current on the GND Pin vs Output Current



$C_{OUT} = 1 \mu F$, $I_{OUT} = 0 \text{ mA}$

Figure 6. Quiescent Current vs Input Voltage

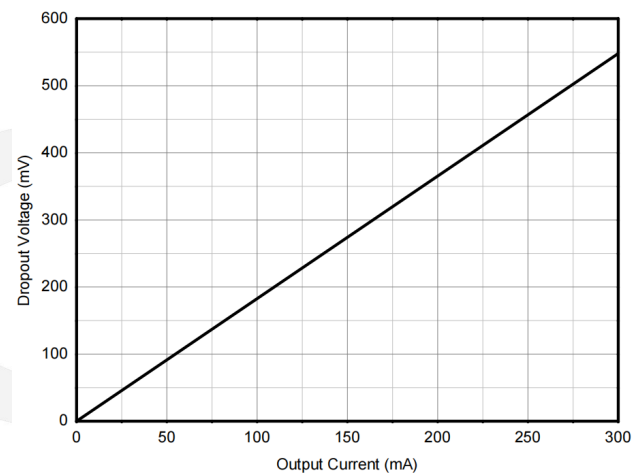
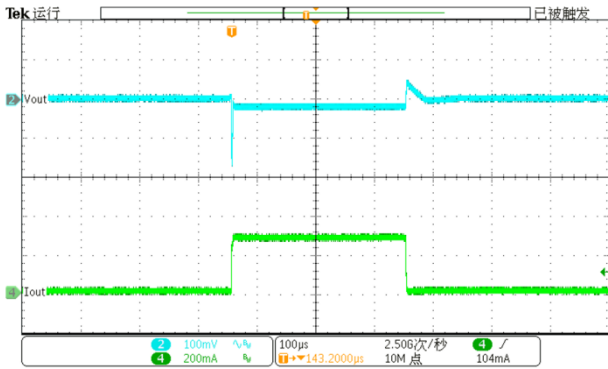


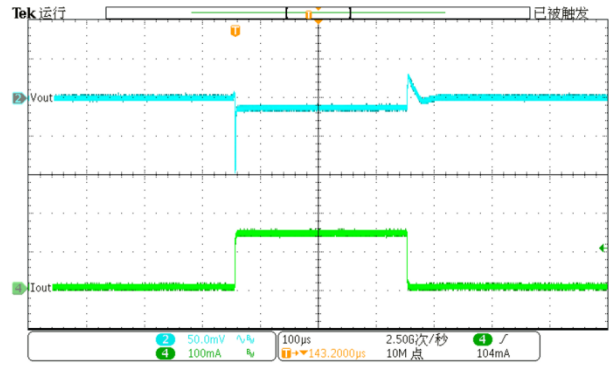
Figure 7. Dropout Voltage vs Output Current



$V_{IN}=2.5\text{ V}$, $V_{OUT}=1.2\text{ V}$, $C_{IN}=C_{OUT}=1\text{ }\mu\text{F}$

Figure 8. Load Transient Response at Load

Step from 1 mA to 300 mA, $V_{OUT} = 1.2\text{ V}$



$V_{IN}=2.5\text{ V}$, $V_{OUT}=1.2\text{ V}$, $C_{IN}=C_{OUT}=1\text{ }\mu\text{F}$

Figure 9. Load Transient Response at Load

Step from 1mA to 150mA, $V_{OUT} = 1.2\text{ V}$

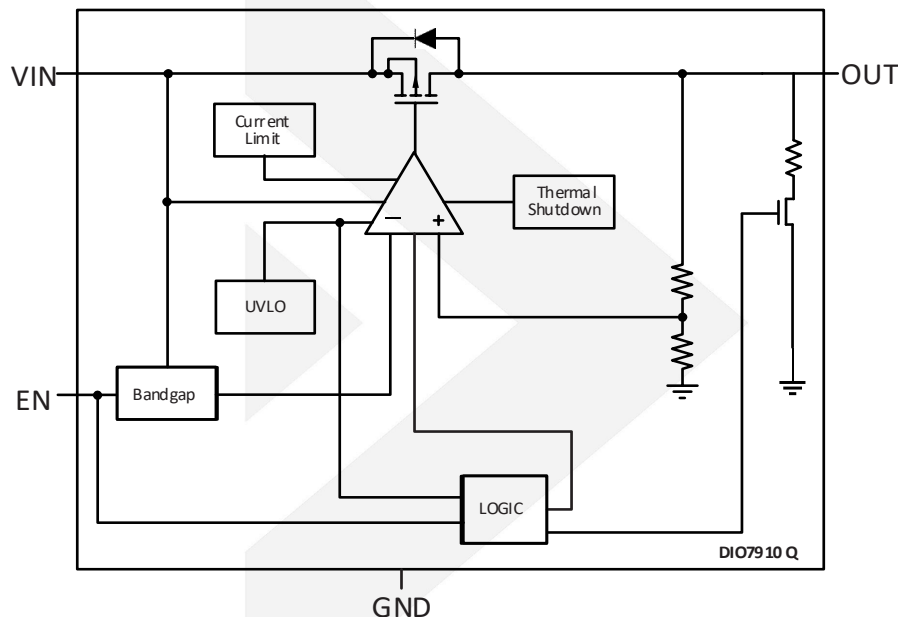
dioo

Detailed Description

Overview

The DIO7910Q series of LDO linear regulators are low quiescent current devices with excellent line and load transient performance. These LDOs are designed for power-sensitive applications. A precision bandgap and error amplifier provide overall 1% accuracy. Low output noise, very high PSRR, and low dropout voltage make this series of devices ideal for most battery-operated handheld equipment. All device versions have integrated thermal shutdown, and current limit.

Block Diagram



Internal Current Limit

The DIO7910Q internal current limit helps to protect the regulator during fault conditions. During the current limit, the output sources a fixed amount of current that is largely independent of the output voltage. In such a case, the output voltage is not regulated and $V_{OUT} = I_{CL} \times R_{LOAD}$. The PMOS pass transistor dissipates $(V_{IN} - V_{OUT}) \times I_{CL}$ until the thermal shutdown is triggered and the device turns off. As the device cools down, it is turned on by the internal thermal shutdown circuit. If the fault condition continues, the device cycles between the current limit and thermal shutdown.

The PMOS pass element in the DIO7910Q has a built-in body diode that conducts current when the voltage at OUT exceeds the voltage at IN. This current is not limited, so if extended reverse voltage operation is anticipated, external limiting to 5% of the rated output current is recommended.

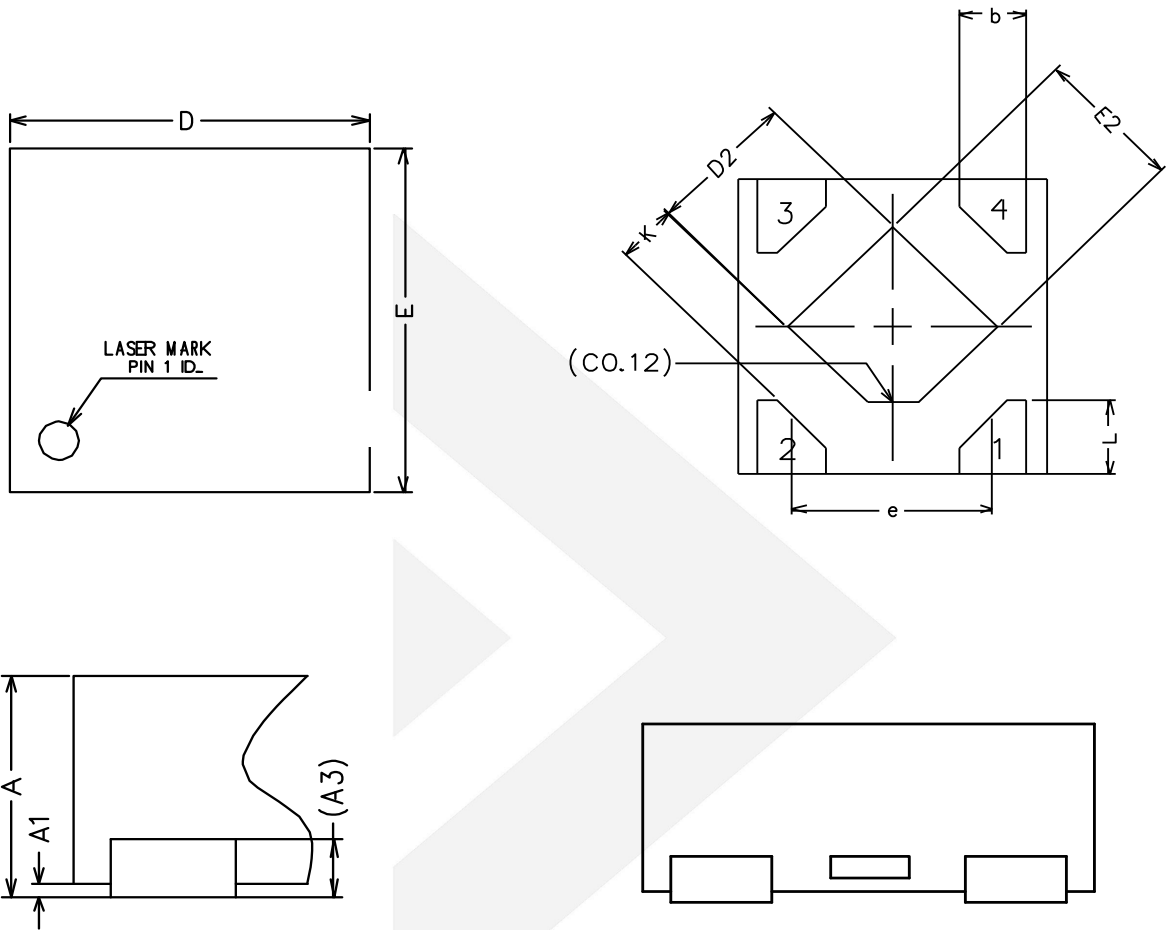
Shut down

The enable pin (EN) is active high. The device is enabled when voltage at EN pin goes above 1 V. The device is turned off when the EN pin is held at less than 0.4 V. When shutdown capability is not required, EN can be connected to the IN pin.

Dropout Voltage

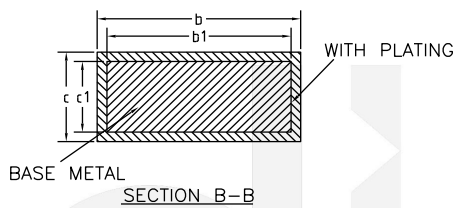
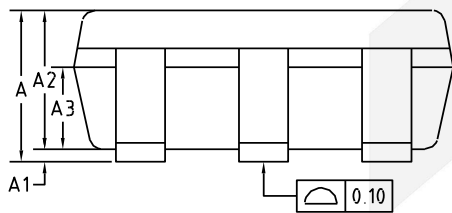
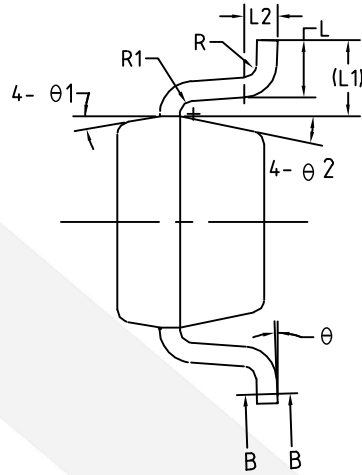
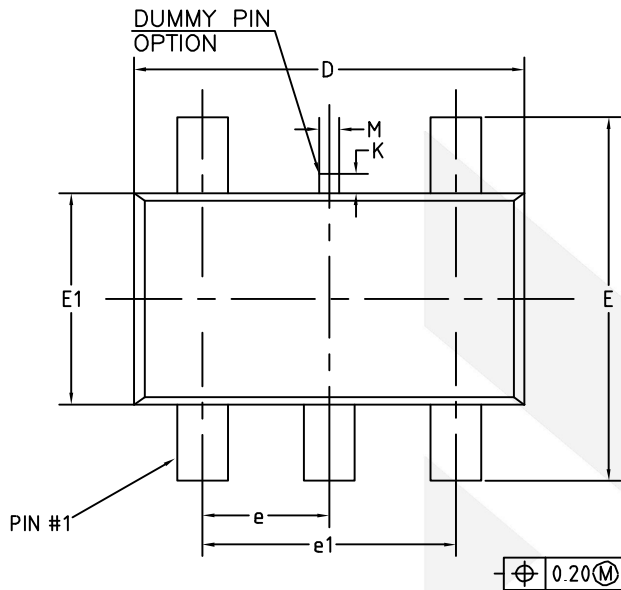
The DIO7910Q uses a PMOS pass transistor to achieve low dropout. When $(V_{IN} - V_{OUT})$ is less than the dropout voltage (V_{DO}), the PMOS pass device is in the linear region of operation and the input-to-output resistance is the $R_{DS(on)}$ of the PMOS pass element. V_{DO} scales approximately with output current because the PMOS device behaves as a resistor in dropout.

Physical Dimensions: DFN 1*1-4



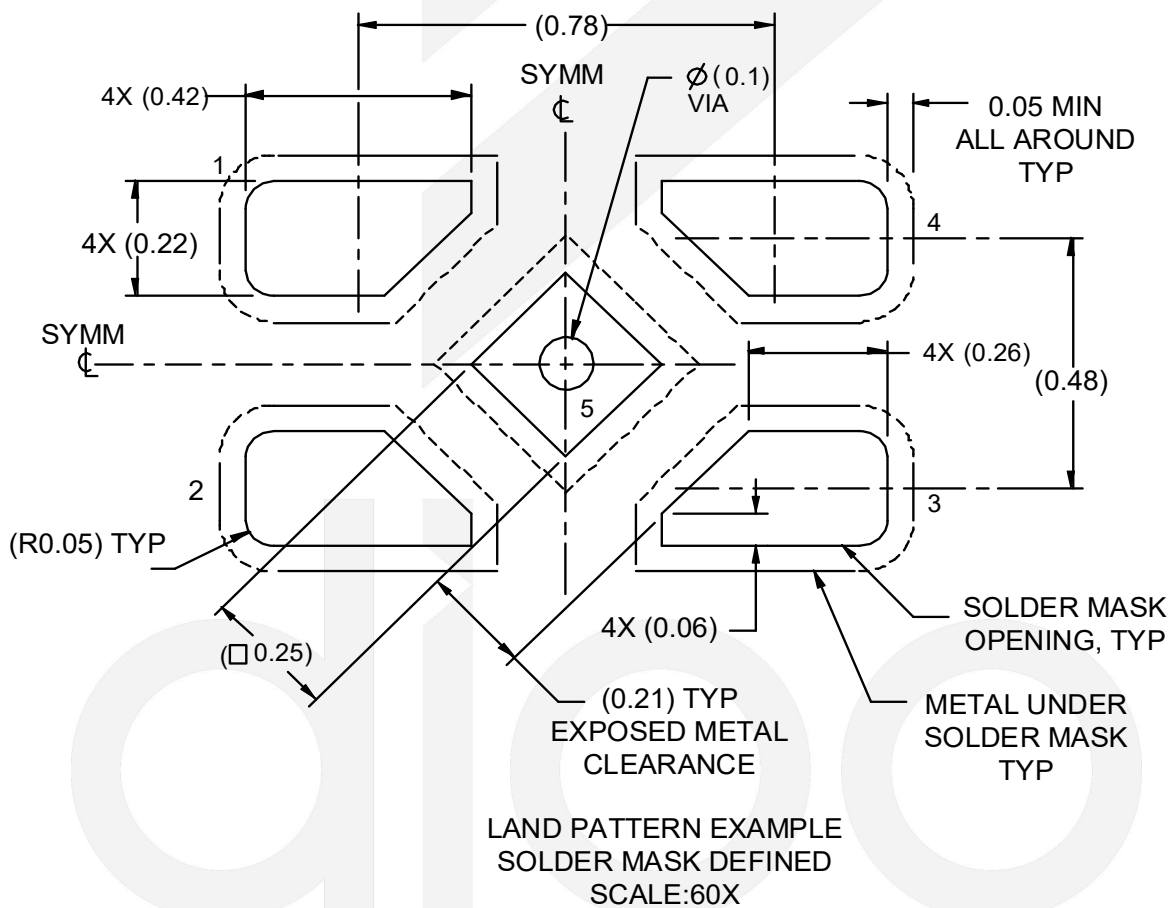
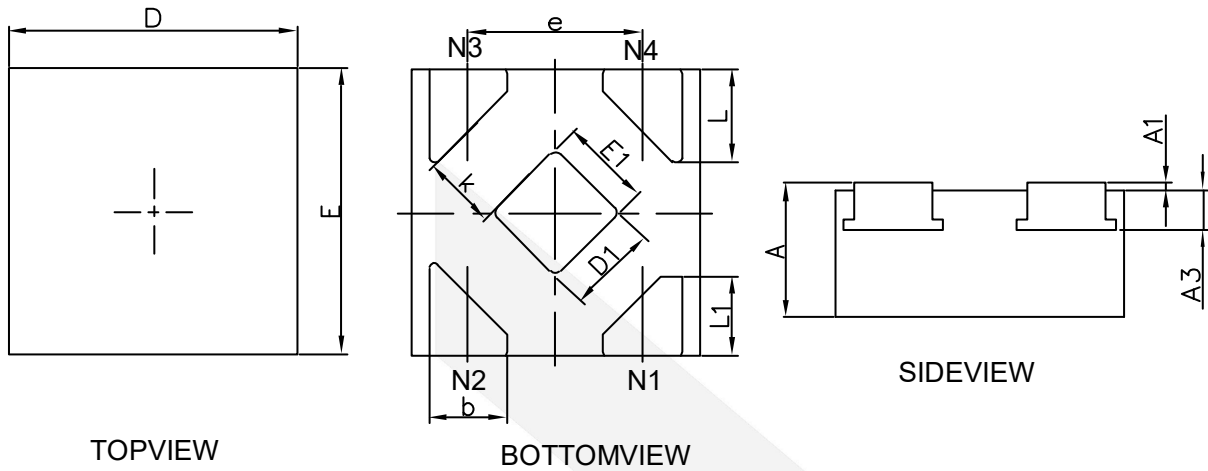
COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	0.34	0.37	0.40
A1	0	0.02	0.05
A3	0.10 REF		
b	0.17	0.22	0.27
D	0.95	1.00	1.05
E	0.95	1.00	1.05
D2	0.43	0.48	0.53
E2	0.43	0.48	0.53
L	0.20	0.25	0.30
e	0.60	0.65	0.70
K	0.15	-	-

Physical Dimensions: SOT23-5



Symbol	Dimensions in Millimeters		
	Min.	Typ.	Max.
A	-	-	1.25
A1	0	-	0.15
A2	1.00	1.10	1.20
A3	0.60	0.65	0.70
b	0.36	-	0.45
b1	0.35	0.38	0.41
c	0.14	-	0.20
c1	0.14	0.15	0.16
D	2.826	2.926	3.026
E	2.60	2.80	3.00
E1	1.526	1.626	1.726
e	0.90	0.95	1.00
e 1	1.80	1.90	2.00
K	0	-	0.25
L	0.30	0.40	0.60
L1		0.59REF	
L2		0.25BSC	
M	0.10	0.15	0.25
R	0.05	-	0.20
R1	0.05	-	0.20
θ	0°	-	8°
$\theta 1$	8°	10°	12°
$\theta 2$	10°	12°	14°

Physical Dimensions: DFN0.8*0.8-4



COMMON DIMENSIONS (UNITS OF MEASURE=MILLIMETER)			
Symbol	MIN	NOM	MAX
A	0.320	-	0.400
A1	-0.004	-	0.046
A3	0.110REF.		
D	0.750	-	0.850
E	0.750	-	0.850
D1	0.200	-	0.300
E1	0.200	-	0.300
k	0.150MIN.		
b	0.170	-	0.270
e	0.480TYP.		
L	0.210	-	0.320
L1	0.170	-	0.270

CONTACT US

Dioo is a professional design and sales corporation for high-quality and performance analog semiconductors. The company focuses on industry markets, such as cell phones, handheld products, laptops, medical equipment, and so on. Dioo's product families include analog signal processing and amplifying, LED drivers, and charger ICs. Go to <http://www.dioo.com> for a complete list of Dioo product families. For additional product information or full datasheet, please contact our sales department or representatives.